

TOSHIBA Transistor Silicon NPN Epitaxial Type

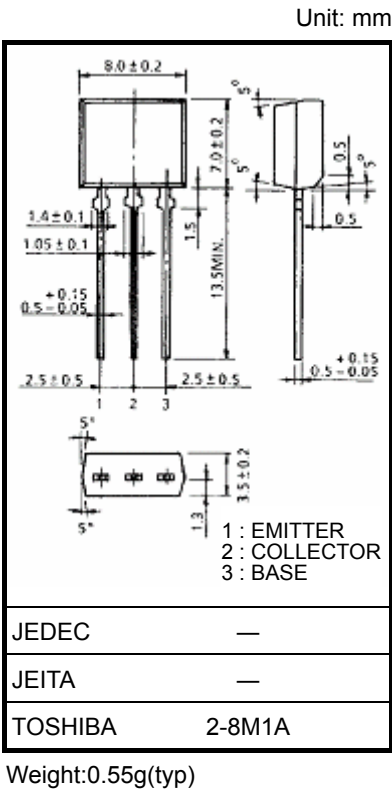
2SC6075

Power Amplifier Applications
Power Switching Applications

Low collector emitter saturation voltage
: $V_{CE(sat)} = 0.5\text{ V (max)}$ ($I_C = 1\text{ A}$)
High-speed switching: $t_{stg} = 0.4\text{ }\mu\text{s (typ)}$

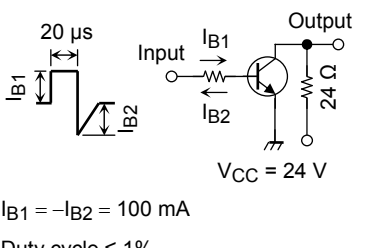
Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	160	V
Collector-emitter voltage		V_{CEX}	160	V
		V_{CEO}	80	V
Emitter-base voltage		V_{EBO}	9	V
Collector current	DC	I_C	2.5	A
	Pulse	I_{CP}	5.0	A
Base current		I_B	1.0	A
Collector power dissipation		P_C	1.3	W
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	-55~150	°C

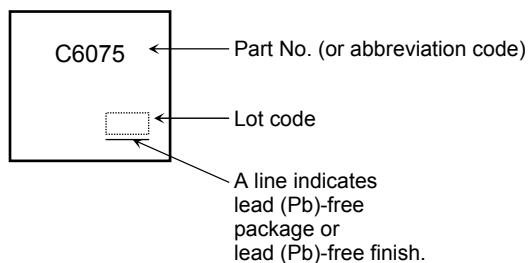


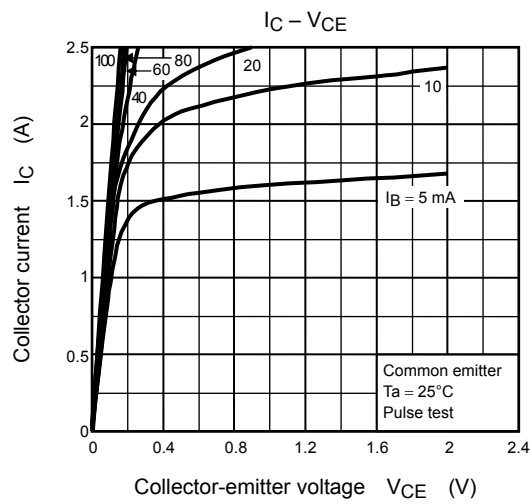
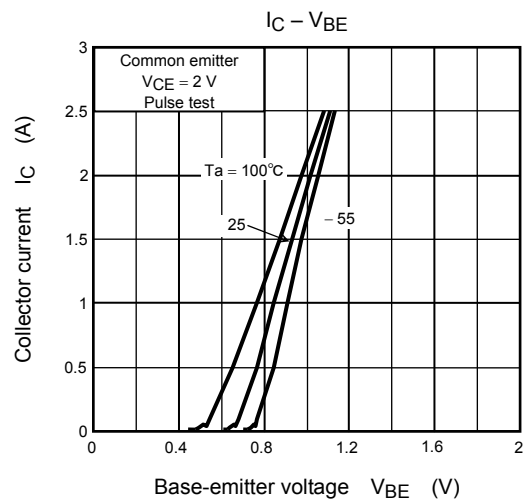
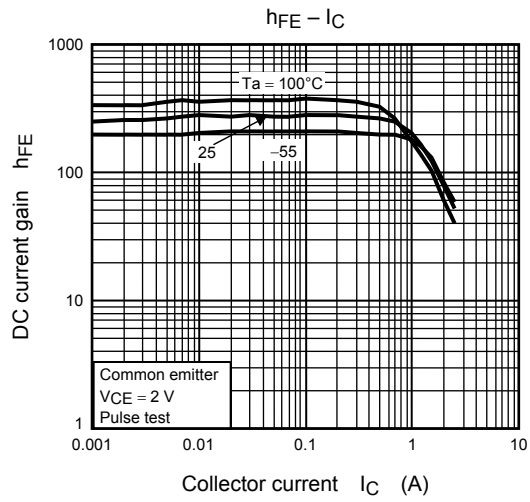
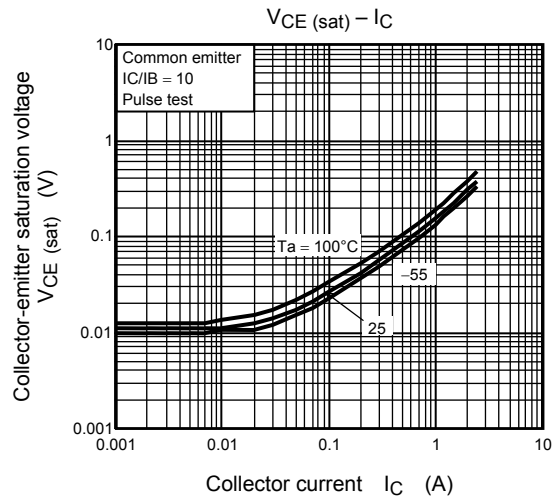
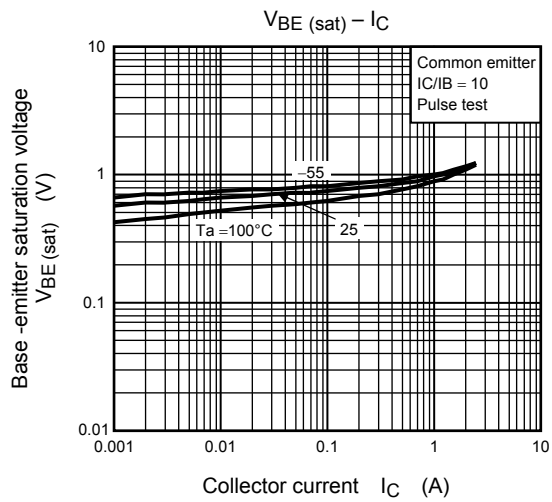
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

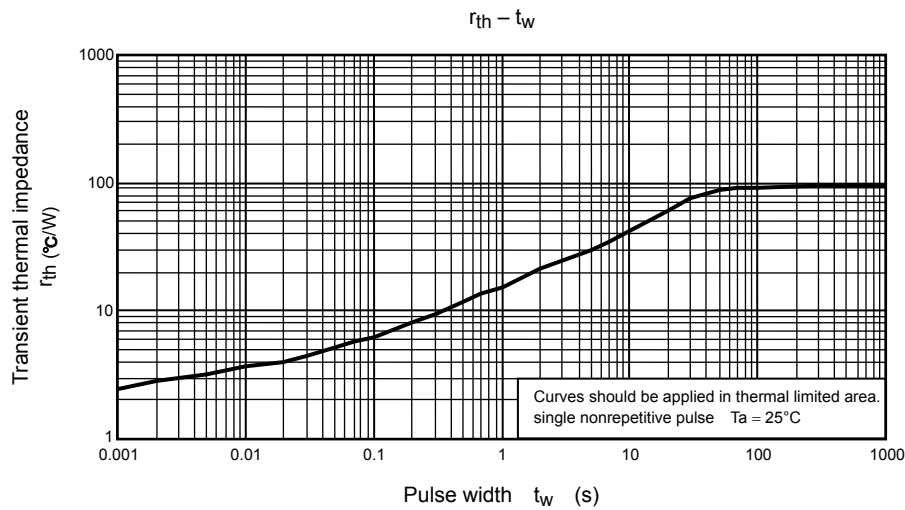
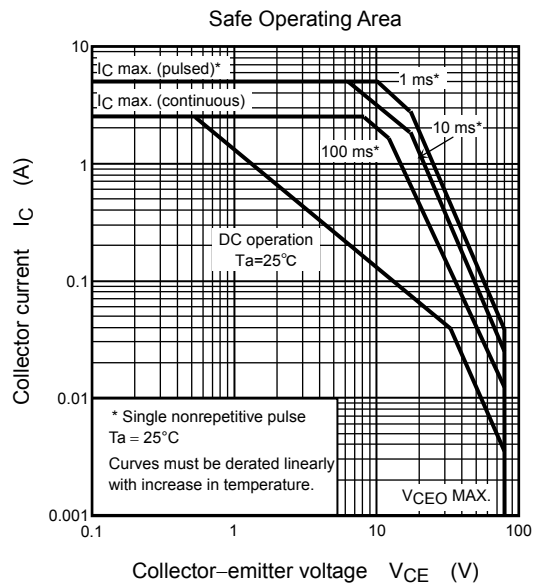
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Conditions	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	$V_{CB} = 160 \text{ V}, I_E = 0$	—	—	1	μA
Emitter cut-off current		I_{EBO}	$V_{EB} = 9 \text{ V}, I_C = 0$	—	—	1	μA
Collector-emitter breakdown voltage		$V_{(BR) CEO}$	$I_C = 10 \text{ mA}, I_B = 0$	80	—	—	V
DC current gain		$h_{FE} (1)$	$V_{CE} = 2 \text{ V}, I_C = 1 \text{ mA}$	150	—	—	
		$h_{FE} (2)$	$V_{CE} = 2 \text{ V}, I_C = 0.5 \text{ A}$	180	—	450	
		$h_{FE} (3)$	$V_{CE} = 2 \text{ V}, I_C = 1 \text{ A}$	100	—	—	
Collector emitter saturation voltage		$V_{CE (sat) (1)}$	$I_C = 0.5 \text{ A}, I_B = 50 \text{ mA}$	—	—	0.3	V
		$V_{CE (sat) (2)}$	$I_C = 1 \text{ A}, I_B = 100 \text{ mA}$	—	—	0.5	V
Base-emitter saturation voltage		$V_{BE (sat)}$	$I_C = 1 \text{ A}, I_B = 100 \text{ mA}$	—	—	1.5	V
Transition frequency		f_T	$V_{CE} = 2 \text{ V}, I_C = 0.5 \text{ A}$	—	150	—	MHz
Collector output capacitance		C_{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	—	14	—	pF
Switching time	Rise time	t_r		—	0.05	—	μs
	Storage time	t_{stg}		—	0.4	—	
	Fall time	t_f		—	0.15	—	

Marking







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